



600V N-Channel Depletion-Mode MOSFET

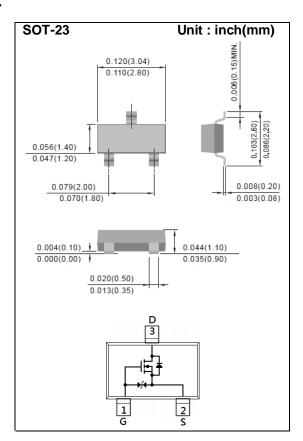
Voltage 600 V Current 30mA

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@16mA<700\Omega$
- R_{DS(ON)}, V_{GS}@0V,I_D@3mA<700Ω
- · Fast switching.
- Improved dv/dt capability
- Improved ESD ability
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: 126



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETEI	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	600	V
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	30	mA
Pulsed Drain Current		I _{DM}	120	mA
Power Dissipation	T _C =25°C	P_{D}	500	mW
	Derate above 25°C		0.004	W/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Thermal resistance				
- Junction to Ambient		$R_{\theta JA}$	250	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =-5V,I _D =250uA	600	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=3V,I_{D}=8uA$	-2.7	-1.9	-1	٧		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =0V,I _D =3mA	-	350	700	Ω		
		V _{GS} =10V,I _D =16mA	-	420	700			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =25V,V _{GS} =0V	12	23	40	mA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	<u>+</u> 0.1	<u>+</u> 10	uA		
Diode Forward Voltage	V_{SD}	I _S =16mA,V _{GS} =-5V	-	0.83	1.2	V		
Dynamic ^(Note 3)								
Total Gate Charge	Q_g	V _{DS} =400V, I _D =0.01A, V _{GS} =-5V to 5V ^(Note 1,2)	-	1.9	-	nC		
Gate-Source Charge	Q_{gs}		-	0.9	-			
Gate-Drain Charge	Q_{gd}		-	0.7	-			
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =-5V, f=1.0MHZ	-	101	-	pF		
Output Capacitance	Coss		-	9.5	-			
Reverse Transfer Capacitance	Crss		-	6	-			
Turn-On Delay Time	td _(on)	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	-	20	-	ns		
Turn-On Rise Time	t _r		-	92	-			
Turn-Off Delay Time	td _(off)		-	95	-			
Turn-Off Fall Time	t _f		-	210	-			
Drain-Source Diode								
Maximum Continuous Drain-Source			_	_	0.03	А		
Diode Forward Current	I _S		_	-				
Maximum Pulsed Drain-Source	I _{SM}		_	_	0.12	А		
Diode Forward Current	'SM			_	0.12			
Reverse Recovery Time	trr	V _{GS} =300V, I _S =0.01A	-	370	-	ns		
Reverse Recovery Charge	Qrr	$dI_F/dt=100A/us^{(Note 2)}$	-	960	-	uC		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

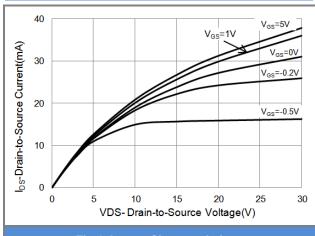


Fig.1 Output Characteristics

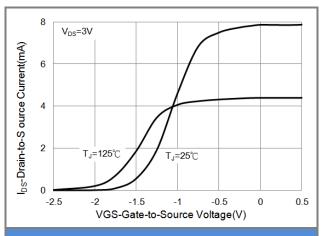


Fig.2 Transfer Characteristics

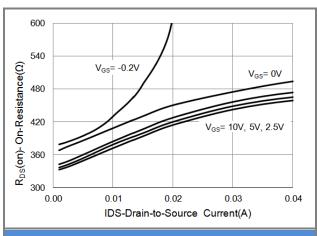


Fig.3 On-Resistance vs. Drain Current

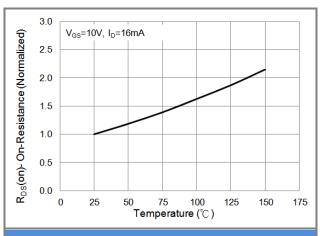


Fig.4 On-Resistance vs. Junction Temperature

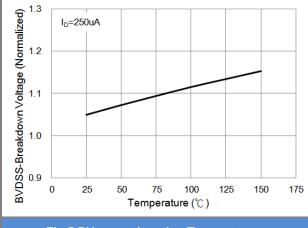


Fig.5 BV_{DSS} vs. Junction Temperature

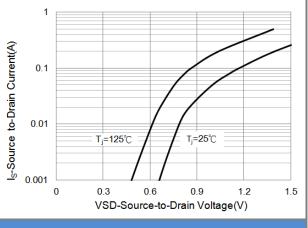


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

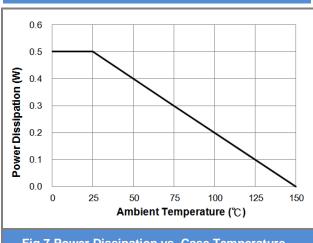


Fig.7 Power Dissipation vs. Case Temperature

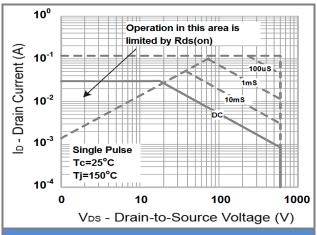


Fig.8 Maximum Safe Operating Area

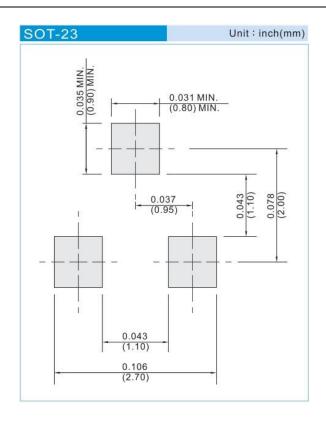




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
BSS126_R1_00001	SOT-23	3K pcs / 7" reel	126	Halogen free
BSS126_R2_00001	SOT-23	12K pcs / 13" reel	126	Halogen free

MOUNTING PAD LAYOUT







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